

10997 U.S. PTO  
10/07/593  
02/13/02

P  
**U.S. UTILITY Patent Application**

**PATENT NUMBER and  
ISSUE DATE**

APPL NUM 10075193	FILING DATE 02/13/2002	CLASS 438	SUBCLASS 253	GAU 2813	EXAMINER Yonrk HUYNH
----------------------	---------------------------	--------------	-----------------	-------------	-------------------------

\*\*APPLICANTS: Chen Sheilin; Fing Er-Xuan; *yes*

\*\*CONTINUING DATA VERIFIED:  
THIS APPLICATION IS A DIV OF 09/933,913 08/20/2001 *yes*

**BEST AVAILABLE COPY**

*No one*

\*\* FOREIGN APPLICATIONS VERIFIED: *yes*

PG-PUB	DO NOT PUBLISH <input type="checkbox"/>	RESCIND <input type="checkbox"/>	ATTORNEY DOCKET NO
Foreign priority claimed 55 USC 119 conditions met		<input type="checkbox"/> yes <i>no</i> <input type="checkbox"/> yes <i>no</i>	MI22-1927
Verified and Acknowledged Examiners's initials <i>YH</i>		TITLE : Methods of forming a capacitor structure	
U.S.DEP'T. OF COMM./PAT.& TM-PTO-436L(Rev. 12-94)			

NOTICE OF ALLOWANCE MAILED		CLAIMS ALLOWED	
		Total Claims	Print Claim for O.G.
ISSUE FEE		DRAWING	
Amount Due	Date Paid	Sheets Drawg.	Fig.s Drawg.
TERMINAL		Print Fig.	
DISCLAIMER		Application Examiner	
PREPARED FOR ISSUE			
WARNING: The information disclosed herein may be restricted. Unauthorized disclosure may be prohibited by the United States Code Title 35, Sections 122, 181 and 368. Possession outside the U.S. Patent & Trademark Office is restricted to authorized employees and contractors only.			
FILED WITH: <input type="checkbox"/> DISK (CRF) <input type="checkbox"/> CD-ROM (Attached in pocket on right inside flap)			